

IXTH3N200P3HV Information


For Reference Only

Part Number [IXTH3N200P3HV](#)
Manufacturer IXYS
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 2000V 3A TO-247
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IXTH3N200P3HV Specifications

Manufacturer Part Number	IXTH3N200P3HV
Manufacturer	IXYS
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (V _{dss})	2000V
Current - Continuous Drain (I _d) @ 25°C	3A (T _c)
Drive Voltage (Max R _{ds On} , Min R _{ds On})	10V
V _{gs(th)} (Max) @ I _d	5V @ 250μA
Gate Charge (Q _g) (Max) @ V _{gs}	70nC @ 10V
Input Capacitance (C _{iss}) (Max) @ V _{ds}	1860pF @ 25V
V _{gs} (Max)	±20V
FET Feature	-
Power Dissipation (Max)	520W (T _c)
R _{ds On} (Max) @ I _d , V _{gs}	8 Ohm @ 1.5A, 10V
Operating Temperature	-55°C ~ 150°C (T _J)
Mounting Type	Through Hole
Supplier Device Package	TO-247
Package / Case	TO-247-3

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IXTH3N200P3HV Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTH3N200P3HV Payment Methods



IXTH3N200P3HV Shipping Methods



If you have any question about IXTH3N200P3HV, please do not hesitate to contact us!

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